



BSS138Q

50V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)}	I _D T _A = +25°C
50V	3.5Ω @ V _{GS} = 10V	200mA

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

System/Load Switch

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The BSS138Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

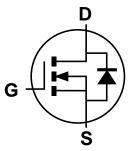
https://www.diodes.com/quality/product-definitions/

Mechanical Data

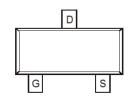
- Case: SOT23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 @
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)







Equivalent Circuit



Top View

Ordering Information (Note 4)

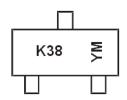
Part Number	Case	Packaging
BSS138Q-7-F	SOT23	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/



Marking Information



 $\begin{array}{l} \text{K38} = \text{Product Type Marking Code} \\ \text{YM} = \text{Date Code Marking} \\ \text{Y or } \overline{\text{Y}} = \text{Year (ex: I} = 2021) \\ \text{M} = \text{Month (ex: 9} = \text{September)} \end{array}$

Date Code Key

Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Н	I	J	K	L	М	N	0	Р	R	S	T
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

C	haracteristic	Symbol	Value	Unit
Drain-Source Voltage		VDSS	50	V
Drain-Gate Voltage R _{GS} ≤ 2	20kΩ	V_{DGR}	50	V
Gate-Source Voltage Continuous		Vaca	±20	V
Gate-Source Voltage	Non Repetitive, Pulse Width<50μs	V _{GSS}	±40	V
Drain Current	Continuous	I _D	200	mA
Pulsed Drain Current (10µs	Pulse Duty Cycle = 1%)	I _{DM}	1	A

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	300	mW
Thermal Resistance, Junction to Ambient (Note 5)	Reja	417	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

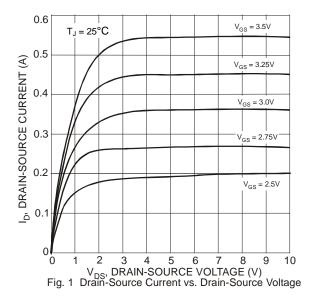
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV _{DSS}	50	75	_	V	$V_{GS} = 0V, I_{D} = 250\mu A$
Zero Gate Voltage Drain Current	IDSS	_	_	0.5	μΑ	$V_{DS} = 50V$, $V_{GS} = 0V$
Gate-Body Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V _{GS(TH)}	0.5	1.2	1.5	>	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
Static Drain-Source On-Resistance	RDS(ON)		1.4	3.5	Ω	$V_{GS} = 10V, I_{D} = 0.22A$
Forward Transconductance	g FS	100	_	_	mS	$V_{DS} = 25V$, $I_{D} = 0.2A$, $f = 1.0kHz$
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	Ciss			50	pF	
Output Capacitance	Coss	_		25	pF	V _{DS} = 10V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	_	8.0	pF	
SWITCHING CHARACTERISTICS (Note 7)						
Turn-On Delay Time	t _{D(ON)}	_		20	ns	Von - 20V In - 0.24 Rosy - 500
Turn-Off Delay Time	tD(OFF)	_		20	ns	$V_{DD} = 30V$, $I_D = 0.2A$, $R_{GEN} = 50\Omega$

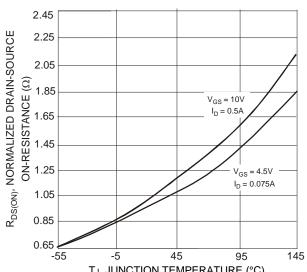
Notes: 5. Device mounted on FR-4 PCB 1.0 x 0.75 x 0.062 inch pad layout as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.

^{6.} Short duration pulse test used to minimize self-heating effect.

^{7.} Guarantee by design. Not subject to production testing.







TJ, JUNCTION TEMPERATURE (°C)
Fig. 3 Drain-Source On-Resistance vs. Junction Temperature

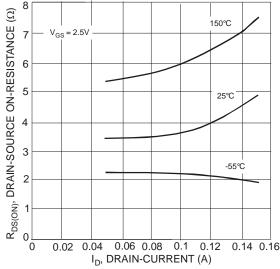
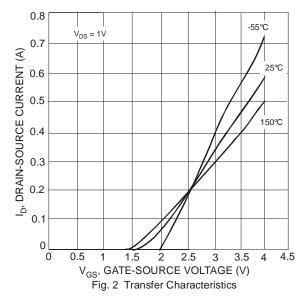
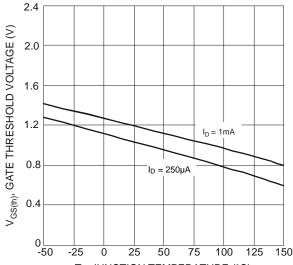


Fig. 5 Drain-Source On-Resistance vs. Drain-Current





T_J, JUNCTION TEMPERATURE (°C)
Fig. 4 Gate Threshold Variation vs. Junction Temperature

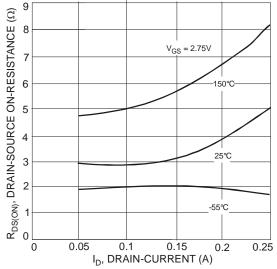


Fig. 6 Drain-Source On-Resistance vs. Drain-Current



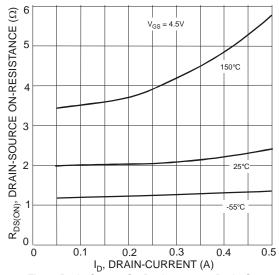
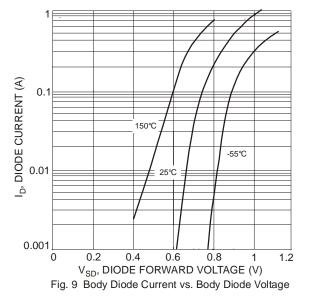


Fig. 7 Drain-Source On-Resistance vs. Drain-Current



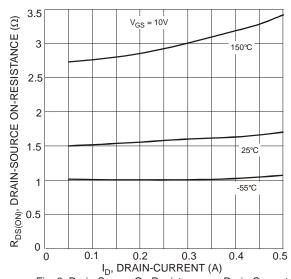


Fig. 8 Drain-Source On Resistance vs. Drain-Current

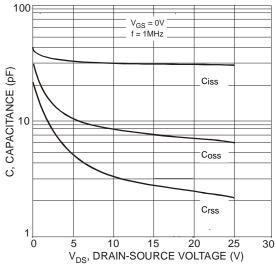


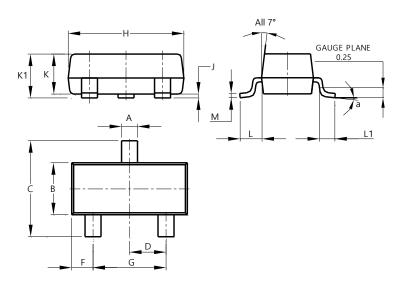
Fig. 10 Capacitance vs. Drain-Source Voltage



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

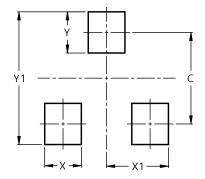


SOT23						
Dim	Min	Max	Тур			
A	0.37	0.51	0.40			
В	1.20	1.40	1.30			
U	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	2.9



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